

Power CoSim+

COSTING TOOL FOR POWER MANUFACTURING

COMPLETE AND POWERFUL MANUFACTURING COSTING TOOL

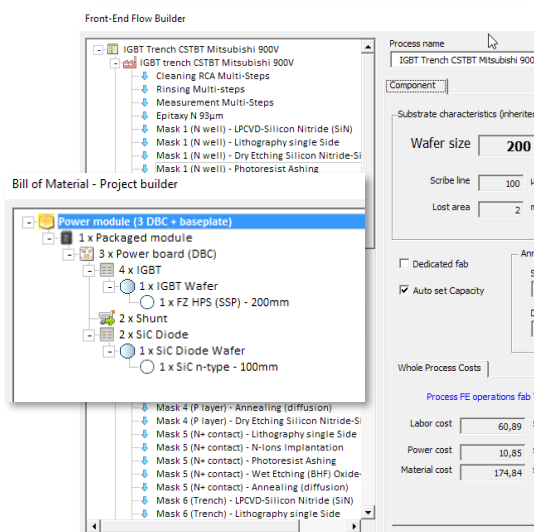
Due to their non-standard manufacturing processes, the power device costs can be difficult to estimate. Components such as superjunction MOSFETs, IGBTs and SiC diodes involve very different process steps.

Power CoSim+ is a flexible tool for evaluating the cost of any semiconductor process or power device, already used by manufacturers and end users.

With the possibility of storing steps and process flows in libraries, this new version dramatically reduces the duration of the cost evaluation.



Step by step, describe your process flow to get a detailed manufacturing cost analysis.



PROCESS-BASED TOOL

Why do you need this tool?

- Optimize your manufacturing cost
- Challenge your own production / process choices
- Create a business plan
- Change your fab and process
- Evaluate economic feasibility
- Simulate your equipment's operating cost

Who should buy this tool?

- Strategic marketing executives
- Process managers
- R&D engineers
- Power equipment suppliers
- Purchasing managers



POWER TYPES

Diodes
MOSFET, JFET
IGBT, BJT
Thyristor
HEMT

PACKAGING

Discretes
Modules
Embedded
Molded

SUBSTRATES

Silicon
SiC
GaN

TECHNOLOGIES

Planar
Trench
Thin Film
Compounds

DATABASE

Equipment
Substrates
Materials
Wafer fab units
Assembly units
etc.

MAIN FEATURES



Multiple process flows

Any power semiconductor process flow can be simulated with hierarchical description for multiple dies or processes, across an unlimited number of process steps or process flows.

Multiple conditions and supply chain

You can set up the tool with your own conditions, including location, clean room class, process type and subcontracting operation parameters.

Results are fully open-format

Modify or export final results, build reports with any Excel workbook.

Safely workgroup-compliant

Secure multiple access, data sharing and data integrity.

Support and updates available

Step Family	Process Sequence / Operation	Equipment	Yield	EQUIPMENT COST (USD / Wafer)	CLEAN ROOM COST (USD / Wafer)	LABOR COST (USD / Wafer)	CONSUMABLE COST (USD / Wafer)	TOTAL COST (USD / Wafer)	Active Equipment needs	Actual allocated Equipment	Equipment UpTime
IGBT Transistor			96.5%	77.07	23.39	64.64	110.11	275.22	Optimal Mode 51798 Wafer / Year		
	IGBT trench Field-Stop 650V		98.50%	67.56	19.96	54.20	83.83	225.54			<=80%
Cleaning/Slipping	Cleaning RCA Multi-Steps	Wafer Cleaning Bench	99.90%	0.32	0.11	0.68	12.72	13.84	0.288	0.360	80%
Cleaning/Slipping	Rinsing Multi-steps	Wafer Cleaning Bench	99.90%	0.07	0.02	0.20	0.21	0.50	0.061	0.076	80%
Measurement	Measurement Multi-Steps	Measurement	99.90%	2.22	1.24	5.21	0.04	8.71	2.370	2.962	80%
Deposition	Mask 1 (LOCOS) - LPCVD-Oxide (SiO2)	LPCVD	99.90%	0.69	0.29	0.45	0.22	1.64	0.155	0.194	80%
Deposition	Mask 1 (LOCOS) - LPCVD-Silicon Nitride (Si3N4)	LPCVD	99.90%	1.18	0.49	0.68	0.72	3.07	0.264	0.331	80%
Lithography	Mask 1 (LOCOS) - Lithography single Side	Patterning single side (coating + Litho etching single - development)	99.90%	1.13	0.10	0.47	2.39	4.09	0.149	0.186	80%
Etching	Mask 1 (LOCOS) - Dry Etching Silicon Nitride (Si3N4)	Plasma Reactbr	99.90%	2.25	0.79	1.82	0.22	5.09	0.672	0.840	80%
Etching	Mask 1 (LOCOS) - Dry Etching Oxide-SiO2	Plasma Reactbr	99.90%	1.16	0.41	1.12	0.15	2.83	0.345	0.431	80%
Thermal Step	Mask 1 (LOCOS) - Thermal wet oxidation (SiO2)	Annealing Furnace 150-450°	99.90%	1.23	0.18	1.52	0.18	3.11	0.688	0.860	80%
Etching	Mask 1 (LOCOS) - Dry Etching Silicon Nitride (Si3N4)	Plasma Reactbr	99.90%	2.25	0.79	1.82	0.22	5.09	0.672	0.840	80%
Cleaning/Slipping	Mask 1 (LOCOS) - Photobresist Ashing	Plasma Asher	99.90%	0.14	0.05	0.81	0.04	1.05	0.200	0.250	80%
Deposition	Mask 2 (toating p-region) - LPCVD-Silicon Nitride (Si3N4)	LPCVD	99.90%	1.18	0.49	0.68	0.72	3.07	0.264	0.331	80%
Lithography	Mask 2 (toating p-region) - Lithography single Side	Patterning single side (coating + Litho etching single - development)	99.90%	1.13	0.10	0.47	2.39	4.09	0.149	0.186	80%
Etching	Mask 2 (toating p-region) - Dry Etching	Plasma Reactbr	99.90%	2.25	0.79	1.82	0.22	5.09	0.672	0.840	80%
Cleaning/Slipping	Mask 2 (toating p-region) - Photobresist Ashing	Plasma Asher	99.90%	0.14	0.05	0.81	0.04	1.05	0.200	0.250	80%
Thermal Step	Mask 2 (toating p-region) - Annealing	Annealing Furnace 150-450°	99.90%	0.07	0.01	0.14	0.01	0.23	0.039	0.049	80%
Implantation	Mask 2 (toating p-region) - P-Ions	Implanter	99.90%	0.50	0.24	0.66	0.95	2.36	0.093	0.116	80%
Etching	Mask 2 (toating p-region) - Dry Etching	Plasma Reactbr	99.90%	2.25	0.79	1.82	0.22	5.09	0.672	0.840	80%

PRICES & CONTACT

Buy Power CoSim+ now

Site licence (one location) – 8,900€*

Corporate licence (worldwide) – 13,300€*

These prices include 12-months' support and database updates, and an online training session. After the first year, we suggest an annual support and update maintenance contract: site - 2,000€ / corporate - 3,000€

*For prices in dollars please use the day's exchange rate / For French customers, add 20 % for VAT.

Contact

For any question, please contact our headquarters in France:

sales@systemplus.fr - +33 2 40 18 09 16

